

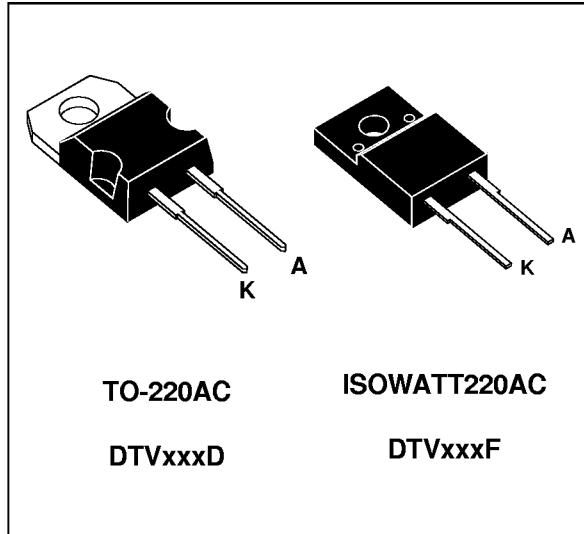


## DTVseries

### (CRT HORIZONTAL DEFLECTION) HIGH VOLTAGE DAMPER DIODE

#### MAIN PRODUCTS CHARACTERISTICS

$I_{F(AV)}$	5 A to 10 A
$V_{RRM}$	1500 V
$V_F$	1.3 V to 1.5 V



#### FEATURES AND BENEFITS

- HIGH BREAKDOWN VOLTAGE CAPABILITY
- VERY FAST RECOVERY DIODE
- SPECIFIED TURN ON SWITCHING CHARACTERISTICS
- LOW STATIC AND PEAK FORWARD VOLTAGE DROP FOR LOW DISSIPATION
- SUITED TO 32-110kHz MONITORS AND 16kHz TV DEFLECTION
- INSULATED VERSION (ISOWATT220AC): Insulating voltage = 2000V DC Capacitance = 12pF
- PLANAR TECHNOLOGY ALLOWING HIGH QUALITY AND BEST ELECTRICAL CHARACTERISTICS

#### DESCRIPTION

High voltage diode with high current capability dedicated to horizontal deflection. DTV16 is optimized to TV meanwhile DTV32 to DTV110 are covering the full range of monitors from the low end to the professional hi-definition SXGA CAD display units.

These devices are packaged either in TO220-AC or in ISOWATT220AC.

#### ABSOLUTE RATINGS

Symbol	Parameter	Value	Unit
$V_{RRM}$	Repetitive peak reverse voltage	1500	V
$I_{F(RMS)}$	RMS forward current	15	A
$I_{FSM}$	Surge non repetitive forward current $t_p = 10\text{ms}$ half sine wave	DTV16	50
		DTV32	75
		DTV56	80
		DTV64	80
		DTV82	80
		DTV110	80
$T_{stg}$	Storage temperature range	-65 to 150	°C
$T_j$	Maximum operating junction temperature	150	°C

## DTVseries

### THERMAL RESISTANCES

Symbol	Parameter	Value		Unit
		TO-220AC	ISOWATT220AC	
$R_{th(j-c)}$	Junction to case thermal resistance	DTV16	3	5.5
		DTV32	2.5	4.75
		DTV56	2	4
		DTV64	1.8	4
		DTV82	1.6	3.7
		DTV110	1.3	3.5

### STATIC ELECTRICAL CHARACTERISTICS

Symbol	Test Conditions	Value				Unit	
		$T_j = 25^\circ\text{C}$		$T_j = 125^\circ\text{C}$			
		Typ	Max	Typ	Max		
$V_F$ *	$I_F = 5 \text{ A}$	DTV16		1.6	1.0	1.5	V
	$I_F = 6 \text{ A}$	DTV32		1.5	1.1	1.35	
	$I_F = 6 \text{ A}$	DTV56		1.8	1.1	1.5	
	$I_F = 6 \text{ A}$	DTV64		1.7	1.1	1.4	
	$I_F = 6 \text{ A}$	DTV82		1.8	1.0	1.3	
	$I_F = 10 \text{ A}$	DTV110		2.3	1.15	1.5	
$I_R$ **	$V_R = V_{RRM}$	DTV16	60	100	500	$\mu\text{A}$	
		DTV32	100	100	1000		
		DTV56	100	100	1000		
		DTV64	100	100	1000		
		DTV82	100	100	1000		
		DTV110	100	100	1000		

pulse test : \*  $t_p = 380 \mu\text{s}, \delta < 2\%$

\*\*  $t_p = 5 \text{ ms}, \delta < 2\%$

## RECOVERY CHARACTERISTICS

Symbol	Test Conditions			Typ	Max	Unit
$t_{rr}$	$I_F = 100\text{mA}$ $I_R = 100\text{mA}$ $I_{RR} = 10\text{mA}$	$T_j = 25^\circ\text{C}$	DTV16	1500		ns
			DTV32	850		
			DTV56	750		
			DTV64	750		
			DTV82	675		
			DTV110	625		
$t_{rr}$	$I_F = 1\text{A}$ $dI_F/dt = -50\text{A}/\mu\text{s}$ $V_R = 30\text{V}$	$T_j = 25^\circ\text{C}$	DTV16	200	300	ns
			DTV32	130	175	
			DTV56	110	135	
			DTV64	110	135	
			DTV82	105	125	
			DTV110	95	115	

## TURN-ON SWITCHING CHARACTERISTICS

Symbol	Test Conditions			Typ	Max	Unit
$t_{fr}$	$I_F = 6\text{A}$ $dI_F/dt = 80\text{A}/\mu\text{s}$ $V_{FR} = 3\text{V}$	$T_j = 100^\circ\text{C}$	DTV16	350		ns
			DTV32	570		
			DTV56	350		
			DTV64	350		
			DTV82	270		
			DTV110	250		
$V_{FP}$	$I_F = 6\text{A}$ $dI_F/dt = 80\text{A}/\mu\text{s}$	$T_j = 100^\circ\text{C}$	DTV16	25	34	V
			DTV32	21	28	
			DTV56	19	26	
			DTV64	18	22	
			DTV82	14	18	
			DTV110	11	14	

To evaluate the maximum conduction losses use the following equation :

$$\text{DTV16} \quad P = 1.14 \times I_F(\text{AV}) + 0.072 \times I_F^2(\text{RMS})$$

$$\text{DTV32} \quad P = 1.069 \times I_F(\text{AV}) + 0.047 \times I_F^2(\text{RMS})$$

$$\text{DTV56} \quad P = 1.15 \times I_F(\text{AV}) + 0.059 \times I_F^2(\text{RMS})$$

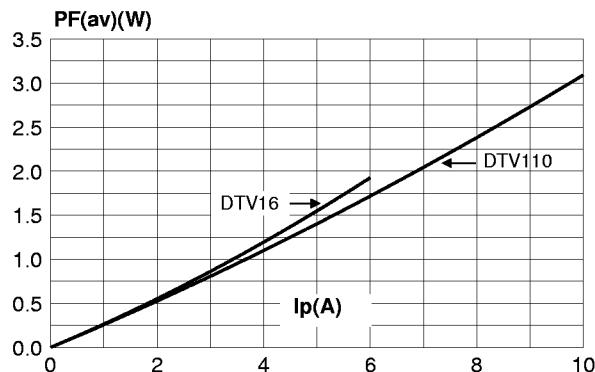
$$\text{DTV64} \quad P = 1.06 \times I_F(\text{AV}) + 0.053 \times I_F^2(\text{RMS})$$

$$\text{DTV82} \quad P = 1.01 \times I_F(\text{AV}) + 0.048 \times I_F^2(\text{RMS})$$

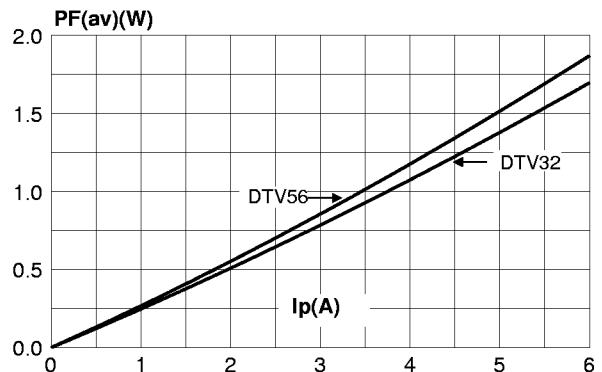
$$\text{DTV110} \quad P = 1.12 \times I_F(\text{AV}) + 0.038 \times I_F^2(\text{RMS})$$

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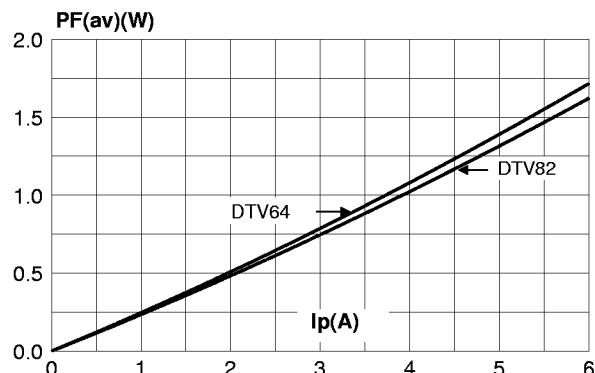
**Fig. 1-1:** Power dissipation versus peak forward current (triangular waveform,  $\delta=0.45$ ).



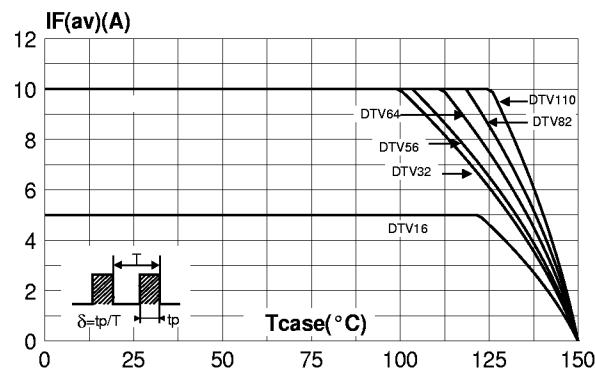
**Fig. 1-2:** Power dissipation versus peak forward current (triangular waveform,  $\delta=0.45$ ).



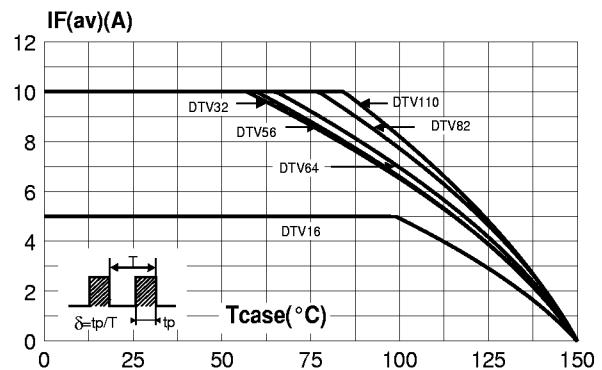
**Fig. 1-3:** Power dissipation versus peak forward current (triangular waveform,  $\delta=0.45$ ).



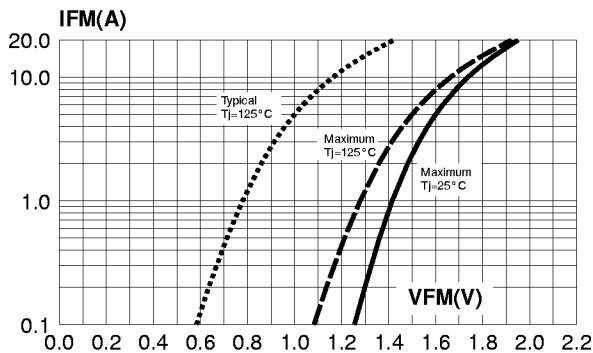
**Fig. 2-1:** Average current versus case temperature ( $\delta=0.5$ ) (TO-220AC).



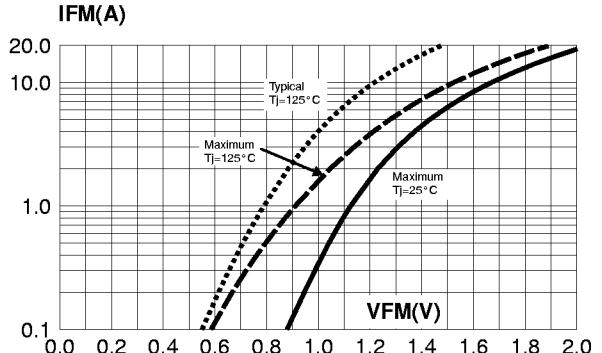
**Fig. 2-2:** Average current versus case temperature ( $\delta=0.5$ ) (ISOWATT220AC).



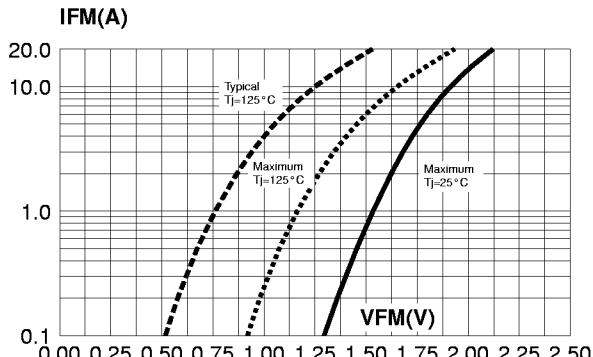
**Fig. 3-1:** Forward voltage drop versus forward current (DTV16D/F).



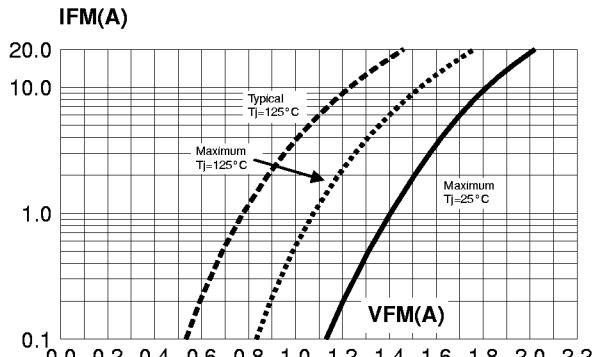
**Fig. 3-2:** Forward voltage drop versus forward current (DTV32D/F).



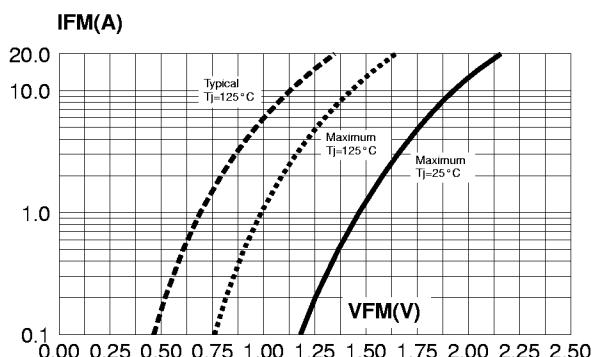
**Fig. 3-3:** Forward voltage drop versus forward current (DTV56D/F).



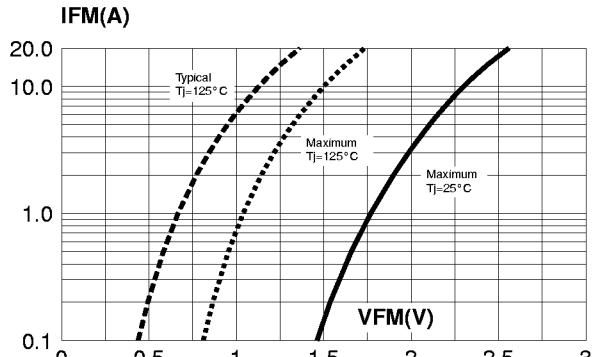
**Fig. 3-4:** Forward voltage drop versus forward current (DTV64D/F).



**Fig. 3-5:** Forward voltage drop versus forward current (DTV82D/F).

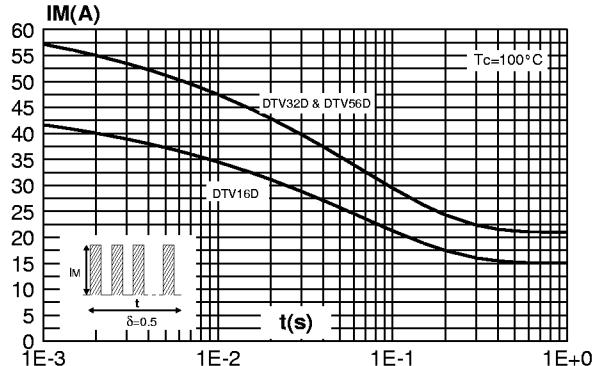


**Fig. 3-6:** Forward voltage drop versus forward current (DTV110D/F).

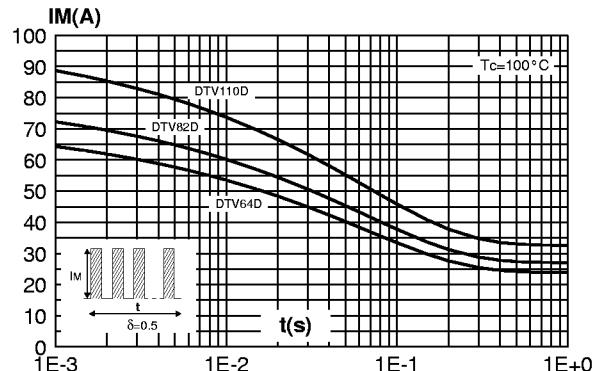


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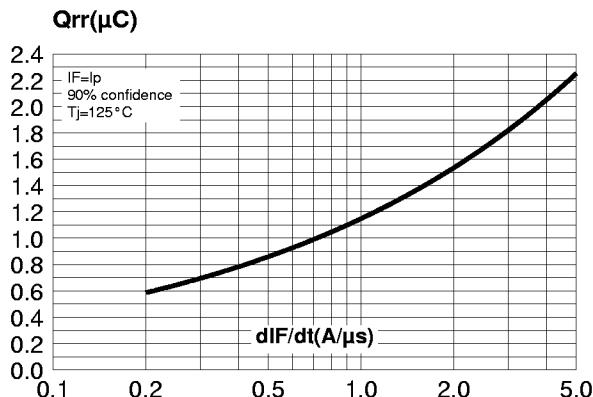
**Fig. 4-1:** Non repetitive surge peak forward current versus overload duration (TO-220AC) (DTV16D / DTV32D / DTV56D).



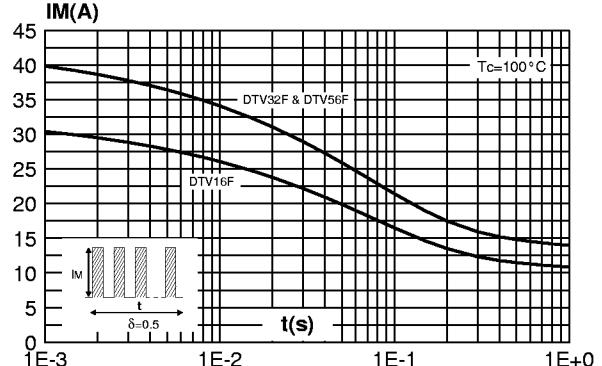
**Fig. 4-3:** Non repetitive surge peak forward current versus overload duration (TO-220AC) (DTV64D / DTV82D / DTV110D).



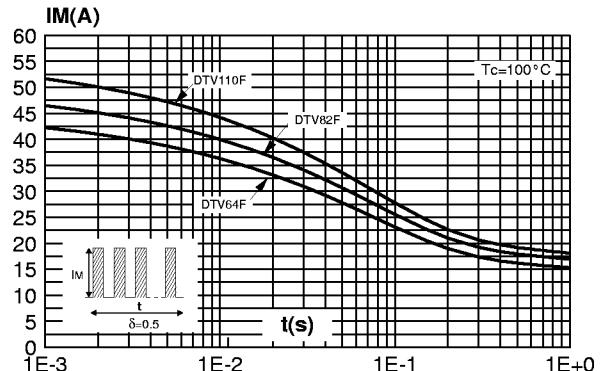
**Fig. 5.1:** Reverse recovery charges versus dIF/dt (DTV16D/F).



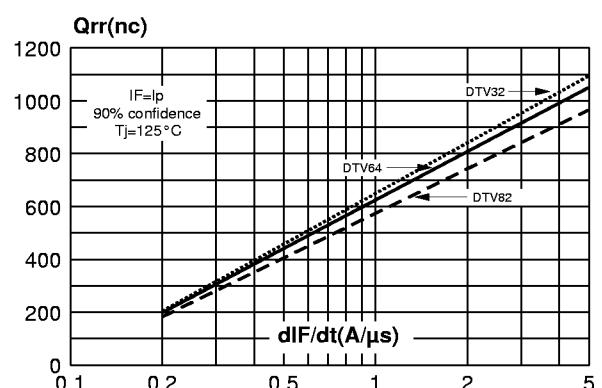
**Fig. 4-2:** Non repetitive surge peak forward current versus overload duration (ISOWATT220AC) (DTV16F / DTV32F / DTV56F).



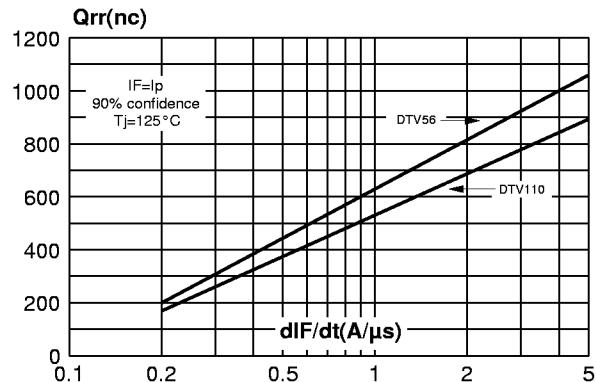
**Fig. 4-4:** Non repetitive surge peak forward current versus overload duration (ISOWATT220AC) (DTV64F / DTV82F / DTV110F).



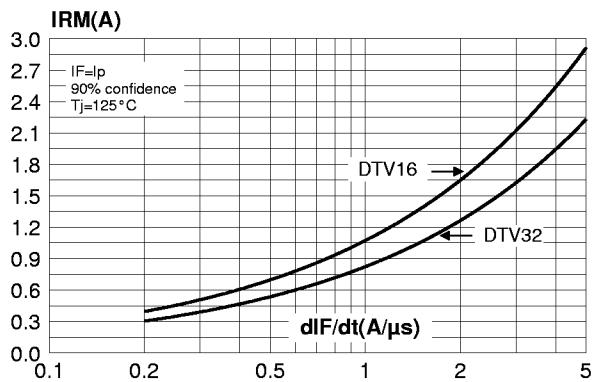
**Fig. 5.2:** Reverse recovery charges versus dIF/dt.



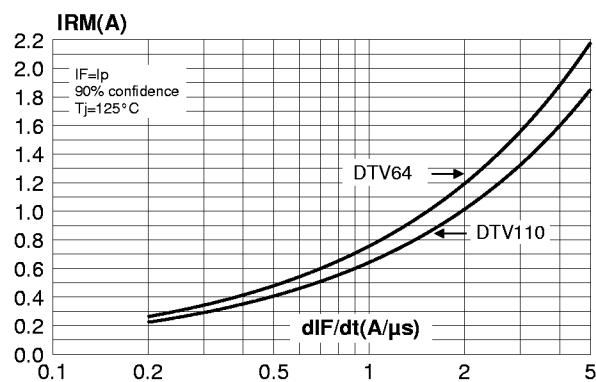
**Fig. 5.3:** Reverse recovery charges versus dIF/dt.



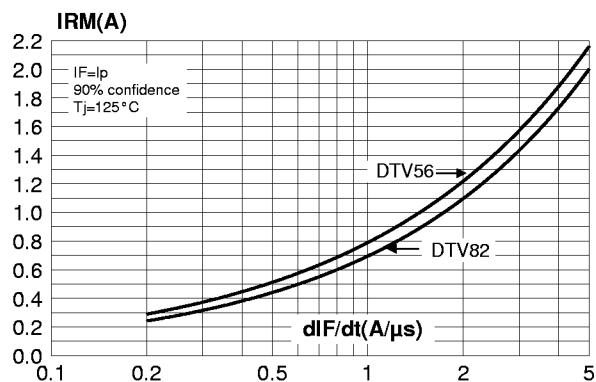
**Fig. 6.1:** Reverse recovery current versus dIF/dt.



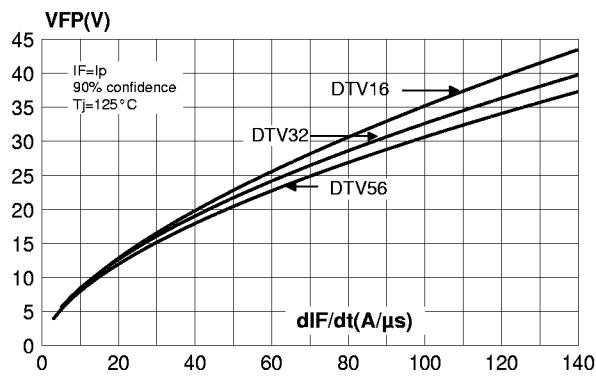
**Fig. 6.2:** Reverse recovery current versus dIF/dt.



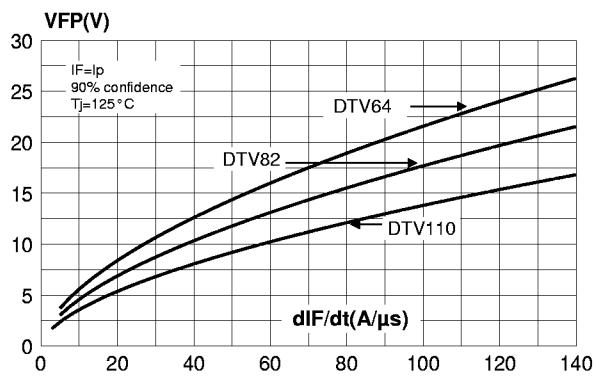
**Fig. 6.3:** Reverse recovery current versus dIF/dt.



**Fig. 7.1:** Transient peak forward voltage versus dIF/dt.

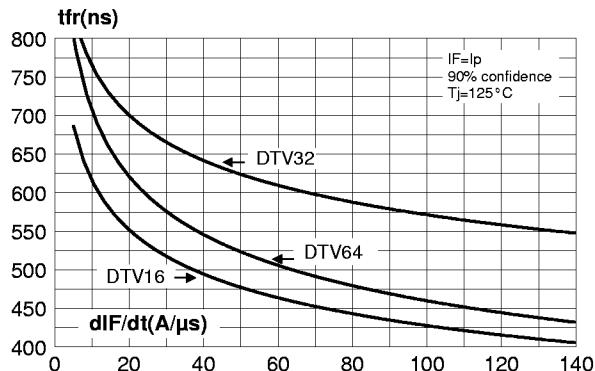


**Fig. 7.2:** Transient peak forward voltage versus dIF/dt.

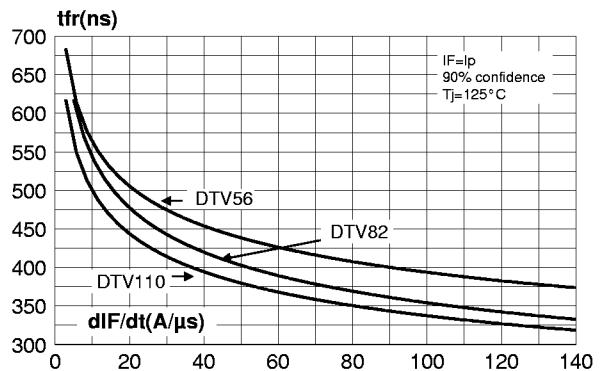


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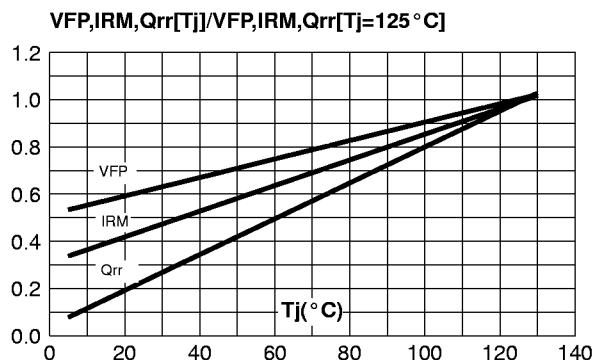
**Fig. 8.1:** Forward recovery time versus dIF/dt.



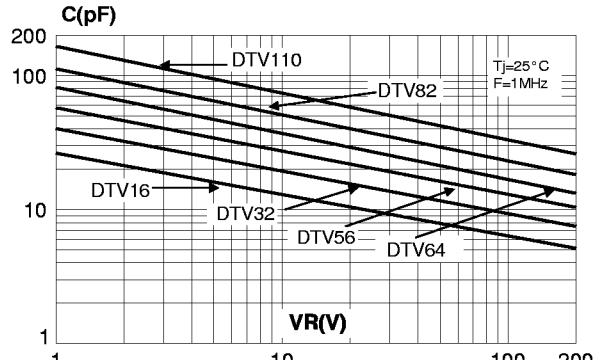
**Fig. 8-2:** Forward recovery time versus dIF/dt.



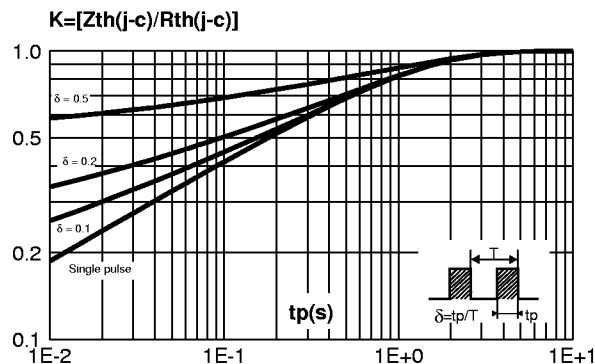
**Fig. 9:** Dynamic parameters versus junction temperature.



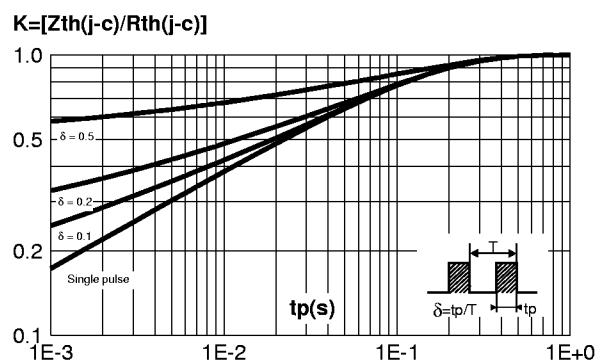
**Fig. 10:** Junction capacitance versus reverse voltage applied (typical values).



**Fig. 11-1:** Relative variation of thermal impedance junction to case versus pulse duration (ISOWATT220AC).

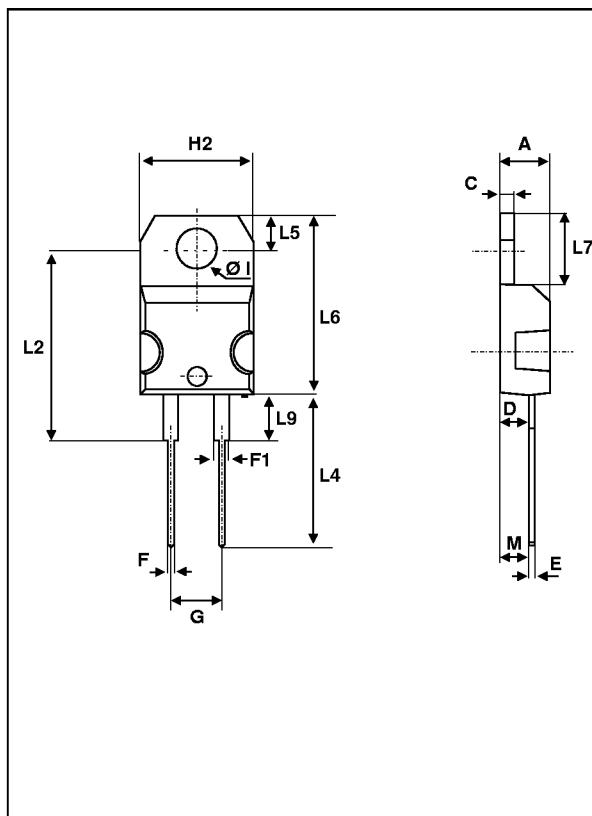


**Fig. 12-2:** Relative variation of thermal impedance junction to case versus pulse duration (TO-220AC).



**PACKAGE DATA**

TO-220AC (plastic) (JEDEC outline)



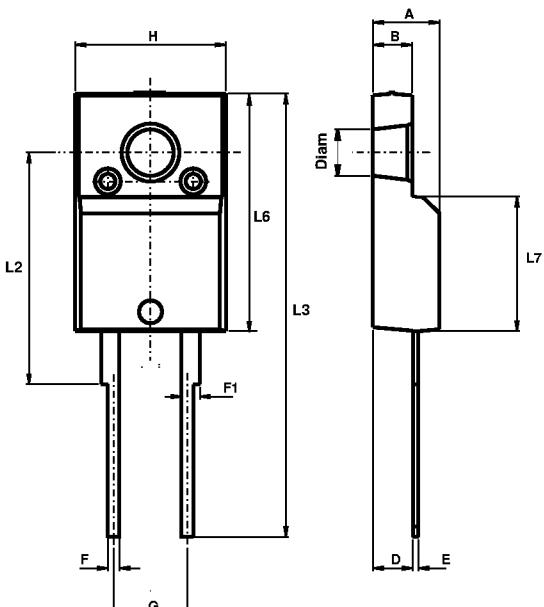
REF.	DIMENSIONS			
	Millimeters		Inches	
	Min.	Max.	Min.	Max.
A	4.40	4.60	0.173	0.181
C	1.23	1.32	0.048	0.051
D	2.40	2.72	0.094	0.107
E	0.49	0.70	0.019	0.027
F	0.61	0.88	0.024	0.034
F1	1.14	1.70	0.044	0.066
G	4.95	5.15	0.194	0.202
H2	10.00	10.40	0.393	0.409
L2	16.40 typ.		0.645 typ.	
L4	13.00	14.00	0.511	0.551
L5	2.65	2.95	0.104	0.116
L6	15.25	15.75	0.600	0.620
L7	6.20	6.60	0.244	0.259
L9	3.50	3.93	0.137	0.154
M	2.6 typ.		0.102 typ.	
Diam. I	3.75	3.85	0.147	0.151

- Cooling method : c.
- Torque value : 0.55 m.N typ (0.70 m.N max).

## DTVseries

### PACKAGE DATA

ISOWATT220AC (plastic)



REF.	DIMENSIONS					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	4.40		4.60	0.173		0.181
B	2.50		2.70	0.098		0.106
D	2.40		2.75	0.094		0.108
E	0.40		0.70	0.016		0.028
F	0.75		1.00	0.030		0.039
F1	1.15		1.70	0.045		0.067
G	4.95		5.20	0.195		0.205
H	10.00		10.40	0.394		0.409
L2		16.00			0.630	
L3	28.60		30.60	1.125		1.205
L6	15.90		16.40	0.626		0.646
L7	9.00		9.30	0.354		0.366
Diam	3.00		3.20	0.118		0.126

- Cooling method : C.
- Electrical isolation : 2000V DC
- Torque value : 0.55 m.N typ (0.70 m.N max).
- Capacitance : 12 pF

Ordering code	Marking	Package	Weight	Base qty	Delivery mode
DTV16D	DTV16D	TO-220AC	1.86g	50	Tube
DTV32D	DTV32D				
DTV56D	DTV56D				
DTV64D	DTV64D				
DTV82D	DTV82D				
DTV110D	DTV110D				
DTV16F	DTV16F	ISOWATT220AC	2g	50	Tube
DTV32F	DTV32F				
DTV56F	DTV56F				
DTV64F	DTV64F				
DTV82F	DTV82F				
DTV110F	DTV110F				

- Epoxy meets UL94, V0

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